compound transistor μ **PA102**

HIGH FREQUENCY NPN TRANSISTOR ARRAY

FEATURES

EC

- TWO BUILT-IN DIFFERENTIAL AMPLIFIER CIRCUITS: (Each Transistor has fr 9 GHz)
- OUTSTANDING hFE LINEARITY
- TWO PACKAGE OPTIONS:

 μ **PA102B:** Superior thermal dissipation due to studded 14-pin ceramic package μ **PA102G:** Reduced circuit size due to 14-pin plastic SOP package for surface mounting

DESCRIPTION AND APPLICATIONS

The μ PA102 is a user configurable Silicon bipolar transistor array consisting of two separate differential amplifiers. It is available in a surface mount (14-pin plastic SOP) package and a 14-pin ceramic package. Typical applications include: pulse pattern generators, oscillators, differential amps, high speed comparators, electro-optic signal processing up to 1 Gigabits/second, and advanced cellular phone systems.

ORDERING INFORMATION

PART NUMBER	PACKAGE	
μPA102B-E1	14-pin ceramic package	
μPA102G-E1	14-pin plastic SOP (225 mil)	

ABSOLUTE MAXIMUM RATINGS (T_A = +25 $^{\circ}$ C)

			,
SYMBOLS	PARAMETERS	UNITS	RATINGS
Vсво*	Collector to Base Voltage	V	15
Vceo*	Collector to Emitter Voltage	V	6
Vebo*	Emitter to Base Voltage	V	2.5
lc*	Collector Current	mA	40
Ρτ	Power Dissipation		
	μPA102B	mW	650
	μPA102G	mW	350
TJ	Junction Temperature		
	μPA102B	°C	200
	μPA102G	°C	125
Tstg	Storage Temperature		
	μPA102B	°C	-55 to +200
	μPA102G	°C	-55 to +125

* Absolute maximum ratings for each transistor.

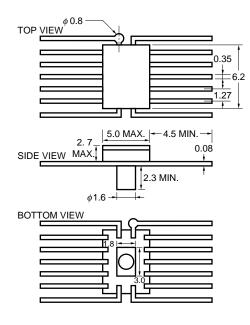
Caution electro-static sensitive devices

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PACKAGE DIMENSIONS (UNIT: mm)

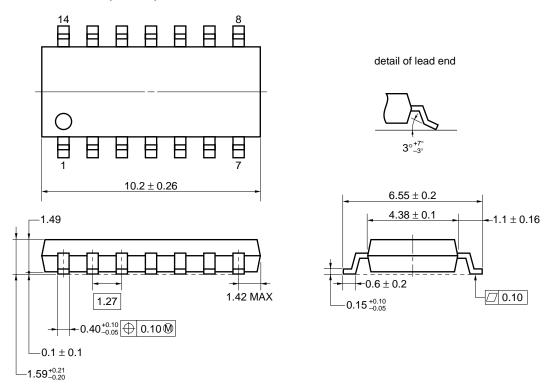
μ**ΡΑ102Β**

14 PIN CERAMIC PACKAGE





★ 14 PIN PLASTIC SOP (225 mil)



NOTE Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.

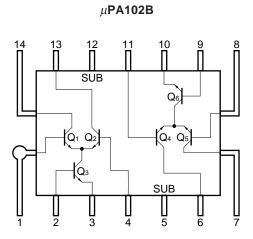
See connection diagram for description of leads.

SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN.	TYP.	MAX.
Ісво	Collector Cutoff Current at V_{CB} = 5 V, I_E = 0 (Q1, Q2, Q4, Q5)	μA			1.0
Іево	Emitter Cutoff Current at $V_{EB} = 1 V$, $Ic = 0$ (Q3, Q6)	μA			1.0
hfe	Direct Current Amplification at $V_{CE} = 3 V$, $I_C = 1 mA$ (Q3, Q6)		40	100	250
hfe1/hfe2	Direct Current Amplification Ratio at V_{CE} = 3 V, Ic = 1 mA, (Q3, Q6)		0.9	1.0	1.1
Ссв	Collector to Base Capacitance at V_{CB} = 3 V, f = 1 MHz (Q1, Q2, Q4, Q5)	pF		0.9	1.8
Сев	Emitter to Base Capacitance at $V_{EB} = 0$, f = 1 MHz (Q3, Q6)	pF		1.4	2.8
Ccs	Collector/Substrate Capacitance at Vcs = 3 V, f = 1 MHz (Q1, Q2, Q4, Q5)	pF		1.4	2.8
f⊤	Gain Bandwidth Product* at V_{CE} = 3 V, Ic = 10 mA	GHz		9.0	

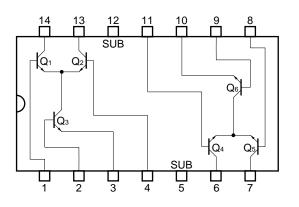
ELECTRICAL CHARACTERISTICS (Unless otherw	se specified T _A = +25 °C μ PA102B, μ PA102G common)
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* Measured by installing a single transistor in a Micro-X package: the value shown is a reference value.

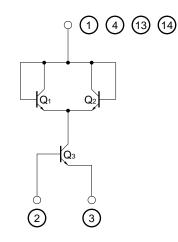
CONNECTION DIAGRAM (Top View)







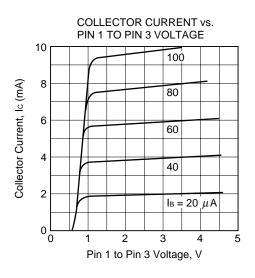
TEST CIRCUIT SCHEMATIC* (For Electrical Characteristics Measurements excluding fr)

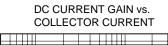


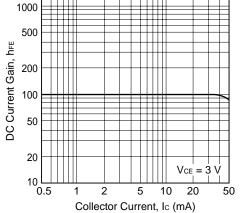
* See performance characteristics for voltage.

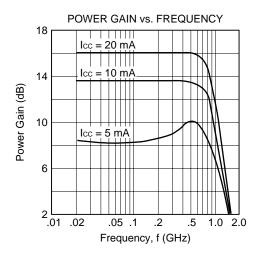
NEC

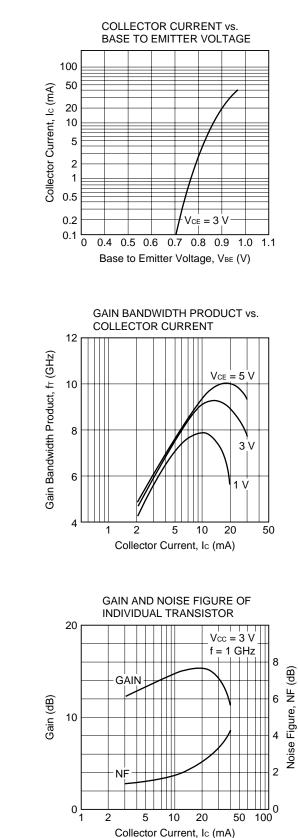












NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as wide as possible to minimize ground impedance (to prevent undesired operation).
- (3) Design circuits connected Sub pin to the lowest voltage to prevent latch-up.
- (4) Design circuits as each pin voltage difference within 15 V maximum.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered in the following recommended conditions. Other soldering methods and conditions than the recommended conditions are to be consulted with our sales representatives.

μ PA102G

Soldering process	Soldering conditions	Recommended condition symbol
Infrared ray reflow	Package peak temperature: 235 °C, Hour: within 30 s. (more than 210 °C), Time: 2 times, Limited days: no. ^{Note}	IR35-00-2
VPS	Package peak temperature: 215 °C, Hour: within 40 s. (more than 200 °C), Time: 2 times, Limited days: no. ^{Note}	VP15-00-2
Wave soldering	Soldering tub temperature: less than 260 °C, Hour: within 10 s. Time: 1 time, Limited days: no. ^{Note}	WS60-00-1
Pin part heating	Pin area temperature: less than 300 °C, Hour: within 3 s./pin Limited days: no. ^{Note}	

μ PA102B

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 230 °C or below, Reflow time: 10 seconds or below (210 °C or higher), Number of reflow process: 1, Exposure limit*: None	
Partial heating method	Terminal temperature: 260 °C or below, Flow time: 10 seconds or below, Exposure limit*: None	

Note It is the storage days after opening a dry pack, the storage conditions are 25 °C, less than 65 % RH.

Caution The combined use of soldering method is to be avoided (However, except the pin area heating method).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

[MEMO]

[MEMO]

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 customer designated "quality assurance program" for a specific application. The recommended applications of
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 - Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
 - Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - Specific: Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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